## **LIST OF CLAIMS**

The list of claims provided below replaces all prior versions and lists of claims in the application. Claims 1, 5, 14, 16 and 21 are currently amended. Claims 4 and 20 are canceled. Accordingly, claims 1-3, 5-19, and 21-29 are pending.

Please amend the claims as follows.

1. (currently amended): An apparatus for determining the critical length of a conductor comprising:

at least one device under test (DUT) <u>including a decoder and selection</u>

<u>circuitry for each said DUT;</u>

said at least one DUT including at least one test strip of a metal under test,
said at least one test strip formed from a series of segments of the
metal under test.

- 2. (original): The apparatus of claim 1, wherein said apparatus includes a plurality of said DUTs, and wherein said segments of each of said plurality of DUTs has a unique length.
- 3. (original): The apparatus of claim 1, wherein said system is configured to detect electromigration in said DUT using Blech's law.
- 4. (canceled).
- 5. (currently amended): The apparatus of claim [[4]] 2, wherein said DUT is embodied within a integrated circuit.

12. (original):

tungsten.

The apparatus of claim 5, wherein said integrated circuit 6. (original): containing said DUT is mounted on a hot chuck. The apparatus of claim 3, wherein said plurality of DUT 7. (original): include metal strips under test ranging in length from approximately 10µm to 320µm. The apparatus of claim 7, wherein said metal strips of said 8. (original): segments are coupled together with segments of a connecting metal. The apparatus of claim 8, wherein said connecting metal 9. (original): segments are approximately three times wider that the corresponding metal strip under test. The apparatus of claim 9, wherein said metal strips under test 10. (original): and said connecting metal are coupled with vias. The apparatus of claim 10, wherein said vias are formed from a 11. (original): electromigration-resistant metal.

13. (original): The apparatus of claim 3, wherein said system is further configured to detect a rising voltage drop across said metal strips under test.

The apparatus of claim 11, wherein said vias of formed from

14. (currently amended): A method for determining the critical length of a conductor comprising:

providing at least one DUT, said at least one DUT including at least one test strip of a metal under test and a decoder and selection circuitry, said at least one test strip formed from a series of segments of the metal under test;

providing a test signal to said at least one DUT; sensing an output signal from said at least one DUT; and determining the critical length of a conductor from said output signal.

- 15. (original): The method of claim 14, wherein said act of determining the critical length of a conductor is performed using Blech's law.
- 16. (currently amended): An apparatus for determining the critical length of a conductor comprising:

DUT including at least one test strip of a metal under test and a

decoder and selection circuitry, said at least one test strip formed from a series of segments of the metal under test;

means for providing a test signal to said testing means;
means for sensing an output signal from said testing means; and
means for determining the critical length of a conductor from said output
signal.

- 17. (original): The apparatus of claim 16, wherein said means for determining the critical length of a conductor is configured to use Blech's law.
- 18. (original): The apparatus of claim 16, wherein said apparatus includes a plurality of said DUTs, and wherein said segments of each of said plurality of DUTs has a unique length.
- 19. (original): The apparatus of claim 16, wherein said system is configured to detect electromigration in said DUT using Blech's law.
- 20. (canceled).
- 21. (currently amended): The apparatus of claim [[20]] 19, wherein said testing means is embodied within a integrated circuit.
- 22. (original): The apparatus of claim 21, wherein said integrated circuit containing said DUT is mounted on a hot chuck.
- 23. (original): The apparatus of claim 18, wherein said plurality of DUTs include metal strips under test ranging in length from approximately 10μm to 320μm.
- 24. (original): The apparatus of claim 23, wherein said metal strips of said segments are coupled together with segments of a connecting metal.

- 25. (original): The apparatus of claim 24, wherein said connecting metal segments are approximately three times wider that the corresponding metal strip under test.
- 26. (original): The apparatus of claim 25, wherein said metal strips under test and said connecting metal are coupled with vias.
- 27. (original): The apparatus of claim 26, wherein said vias are formed from a electromigration-resistant metal.
- 28. (original): The apparatus of claim 27, wherein said vias of formed from tungsten.
- 29. (original): The apparatus of claim 19, wherein said apparatus is further configured to detect a rising voltage drop across said metal strips under test.